

isc N-Channel MOSFET Transistor

DMG4N60SJ3

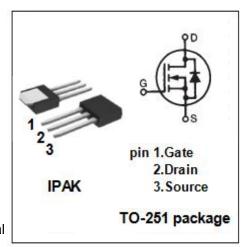
FEATURES

- Drain Current –I_D= 3A@ T_C=25°C
- · Drain Source Voltage-
 - : V_{DSS}= 600V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 2.5 \Omega (Max)$
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



DESCRIPTION

• Designed for use in switch mode power supplies and general purpose applications.

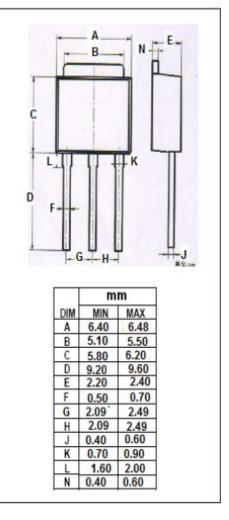


ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|--|---------|------------|
| V _{DSS} | Drain-Source Voltage | 600 | V |
| V _G s | Gate-Source Voltage-Continuous | ±30 | V |
| I _D | Drain Current-Continuous | 3 | А |
| I _{DM} | Drain Current-Single Pluse | 6 | Α |
| P_D | Total Dissipation @T _C =25℃ | 41 | W |
| TJ | Max. Operating Junction Temperature | -55~150 | $^{\circ}$ |
| T _{stg} | Storage Temperature | -55~150 | ℃ |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|---------------------|--------------------------------------|-----|------|
| R _{th j-c} | Thermal Resistance, Junction to Case | 3.0 | °C/W |





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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | MAX | UNIT |
|----------------------|---------------------------------|---|-----|------|------|
| V _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} = 0; I _D = 0.25mA | 600 | | V |
| $V_{GS(th)}$ | Gate Threshold Voltage | V _{DS} = V _{GS} ; I _D = 0.25mA | 2.5 | 4.5 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 10V; I _D = 2A | | 2.5 | Ω |
| I _{GSS} | Gate-Body Leakage Current | V _{GS} = ±30V;V _{DS} = 0 | | ±100 | nA |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} =600V; V _{GS} = 0 | | 1.0 | μА |
| V _{SD} | Forward On-Voltage | I _S = 1A; V _{GS} = 0 | | 1.4 | V |

NOTICE:

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